

## **isc** Silicon PNP Power Transistor

## 2SB857

## DESCRIPTION

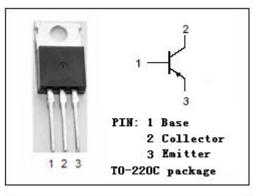
- Collector Current: I<sub>C</sub>= -4A
- Low Collector Saturation Voltage
- : V<sub>CE(sat)</sub>= -1.0V(Max)@I<sub>C</sub>= -2A
- High Collector Power Dissipation
- Complement to Type 2SD1133
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

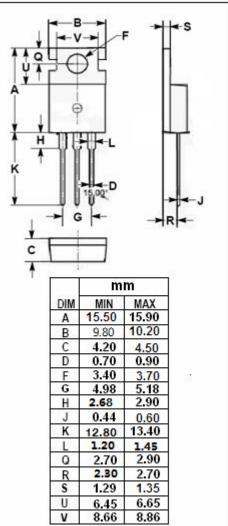
### **APPLICATIONS**

• Designed for low frequency power amplifier applications.

#### ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>CBO</sub>	Collector-Base Voltage	-70	V
Vceo	Collector-Emitter Voltage	-50	V
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V
Ι <sub>C</sub>	Collector Current-Continuous	-4	А
Ісм	Collector Current-Peak	-8	А
Pc	Total Power Dissipation @ T <sub>c</sub> =25℃	40	W
TJ	Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature Range -45~		Ĉ





isc website: www.iscsemi.com



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## **ELECTRICAL CHARACTERISTICS**

#### T<sub>c</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	Ic= -30mA ; R <sub>BE</sub> = ∞	-50			V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> = -1mA ; I <sub>E</sub> = 0	-70			V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = -1mA ; I <sub>C</sub> = 0	-5			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -2A; I <sub>B</sub> = -0.2A			-1.0	V
V <sub>BE</sub> (on)	Base-Emitter On Voltage	I <sub>C</sub> = -1A ; V <sub>CE</sub> = -4V			-1.0	V
Ісво	Collector Cutoff Current	V <sub>CB</sub> = -50V ; I <sub>E</sub> = 0			-1	μA
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = -1A ; V <sub>CE</sub> = -4V	60		320	
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = -0.1A ; V <sub>CE</sub> = -4V	35			
f⊤	Current-Gain—Bandwidth Product	Ic= -0.5A ; V <sub>CE</sub> = -4V		15		MHz

#### h<sub>FE-1</sub> Classifications

В	С	D
60-120	100-200	160-320

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